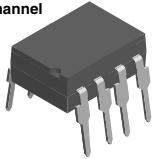
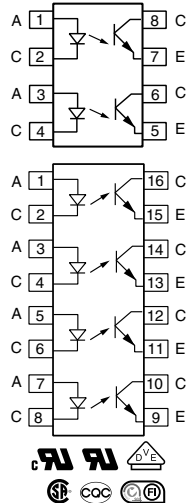
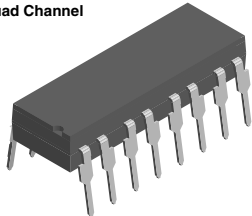


Optocoupler, Phototransistor Output (Dual, Quad Channel)

Dual Channel



Quad Channel



FEATURES

- Alternate source to TLP621-2, TLP621-4 and TLP621GB-2, TLP621GB-4
- High collector emitter voltage, $BV_{CEO} = 70\text{ V}$
- Dual and quad packages feature:
 - Lower pin and parts count
 - Better channel to channel CTR match
 - Improved common mode rejection
- Isolation rated voltage 4420 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT

AGENCY APPROVALS

- [UL](#)
- [cUL](#)
- [DIN EN 60747-5-5 \(VDE 0884-5\)](#), available with option 1
- [CQC GB4943.1](#)
- [CQC GB8898](#)
- [FIMKO](#)

LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The ILD621, ILQ621, ILD621GB, ILQ621GB are multi-channel phototransistor optocouplers that use GaAs IRED emitters and high gain NPN silicon phototransistors. These devices are constructed using double molded insulation technology.

The ILD621, ILQ621GB is well suited for CMOS interfacing given the CTR_{CEsat} of 30 % minimum at I_F of 1.0 mA. High gain linear operation is guaranteed by a minimum CTR_{CE} of 100 % at 5.0 mA. The ILD621, ILQ621 has a guaranteed CTR_{CE} 50 % minimum at 5.0 mA. The transparent ion shield insures stable DC gain in applications such as power supply feedback circuits, where constant DC V_{IO} voltages are present.

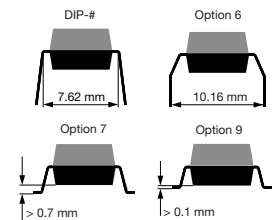
ORDERING INFORMATION



PART NUMBER

PACKAGE OPTION

x = D (Dual) or Q (Quad)



AGENCY CERTIFIED / PACKAGE	DUAL CHANNEL		QUAD CHANNEL	
	CTR (%)			
UL, cUL, CSA, CQC, FIMKO	> 50	> 100	> 50	> 100
DIP-8	-	ILD621GB	-	-
SMD-8, option 7	ILD621-X007T	ILD621GB-X007T	-	-
DIP-16	-	-	ILQ621	ILQ621GB
DIP-16, option 6	-	-	ILQ621-X006	-
SMD-16, option 7	-	-	ILQ621-X007T	-
SMD-16, option 9	-	-	-	ILQ621GB-X009
VDE, UL, cUL, CSA, CQC, FIMKO	> 50	> 100	> 50	> 100
DIP-16	-	-	-	ILQ621GB-X001
SMD-16, option 7	-	-	-	ILQ621GB-X017T

Note

- For additional information on the available options refer to option information



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT					
Reverse voltage			V_R	6.0	V
Forward current			I_F	60	mA
Surge current			I_{FSM}	1.5	A
Power dissipation			P_{diss}	100	mW
Derate from 25 °C				1.33	mW/°C
OUTPUT					
Collector emitter reverse voltage			V_{CEO}	70	V
Collector current			I_C	50	mA
	$t < 1.0\text{ ms}$		I_C	100	mA
Power dissipation			P_{diss}	150	mW
Derate from 25 °C				-2.0	mW/°C
COUPLER					
Package dissipation		ILD621		400	mW
		ILD621GB		400	mW
Derate from 25 °C				5.33	mW/°C
Package dissipation		ILQ621		500	mW
		ILQ621GB		500	mW
Derate from 25 °C				6.67	mW/°C
Storage temperature			T_{stg}	-55 to +150	°C
Operating temperature			T_{amb}	-55 to +100	°C
Junction temperature			T_j	100	°C
Soldering temperature ⁽¹⁾	2.0 mm from case bottom		T_{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 10\text{ mA}$		V_F	1.0	1.15	1.3	V
Reverse current	$V_R = 6.0\text{ V}$		I_R	-	0.01	10	μA
Capacitance	$V_R = 0\text{ V}$, $f = 1.0\text{ MHz}$		C_O	-	40	-	pF
Thermal resistance, junction to lead			R_{THJL}	-	750	-	K/W
OUTPUT							
Collector emitter capacitance	$V_{CE} = 5.0\text{ V}$, $f = 1.0\text{ MHz}$		C_{CE}	-	6.8	-	pF
Collector emitter leakage current	$V_{CE} = 24\text{ V}$		I_{CEO}	-	10	100	nA
			I_{CEO}	-	20	50	μA
Thermal resistance, junction to lead			R_{THJL}	-	500	-	K/W
COUPLER							
Capacitance (input to output)	$V_{IO} = 0\text{ V}$, $f = 1.0\text{ MHz}$		C_{IO}	0.8	-	-	pF
Insulation resistance	$V_{IO} = 500\text{ V}$			10^{12}	-	-	Ω
Channel to channel insulation				500	-	-	VAC
Collector emitter saturation voltage	$I_F = 8.0\text{ mA}$, $I_{CE} = 2.4\text{ mA}$	ILD621	V_{CEsat}	-	-	0.4	V
		ILQ621					
	$I_F = 1.0\text{ mA}$, $I_{CE} = 0.2\text{ mA}$	ILD621GB	V_{CEsat}	-	-	0.4	V
		ILQ621GB					

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Channel/channel CTR match	$I_F = 5.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$		CTR _X /CTR _Y	1 to 1	-	3 to 1	%
Current transfer ratio (collector emitter saturated)	$I_F = 1.0 \text{ mA}$, $V_{CE} = 0.4 \text{ V}$	ILD621	CTR _{CEsat}	-	60	-	%
		ILQ621	CTR _{CEsat}	-	60	-	%
		ILD621GB	CTR _{CEsat}	30	-	-	%
		ILQ621GB	CTR _{CEsat}	30	-	-	%
Current transfer ratio (collector emitter)	$I_F = 5.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$	ILD621	CTR _{CE}	50	80	600	%
		ILQ621	CTR _{CE}	50	80	600	%
		ILD621GB	CTR _{CE}	100	200	600	%
		ILQ621GB	CTR _{CE}	100	200	600	%

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
NON-SATURATED							
On time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 75 \Omega$, 50 % of V_{PP}	t_{on}	-	3.0	-	μs	
Rise time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 75 \Omega$, 50 % of V_{PP}	t_r	-	2.0	-	μs	
Off time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 75 \Omega$, 50 % of V_{PP}	t_{off}	-	2.3	-	μs	
Fall time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 75 \Omega$, 50 % of V_{PP}	t_f	-	2.0	-	μs	
Propagation H to L	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 75 \Omega$, 50 % of V_{PP}	t_{PHL}	-	1.1	-	μs	
Propagation L to H	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 75 \Omega$, 50 % of V_{PP}	t_{PLH}	-	2.5	-	μs	
SATURATED							
On time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 1 \text{ k}\Omega$, $V_{TH} = 1.5 \text{ V}$	t_{on}	-	4.3	-	μs	
Rise time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 1 \text{ k}\Omega$, $V_{TH} = 1.5 \text{ V}$	t_r	-	2.8	-	μs	
Off time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 1 \text{ k}\Omega$, $V_{TH} = 1.5 \text{ V}$	t_{off}	-	2.5	-	μs	
Fall time	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 1 \text{ k}\Omega$, $V_{TH} = 1.5 \text{ V}$	t_f	-	11	-	μs	
Propagation H to L	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 1 \text{ k}\Omega$, $V_{TH} = 1.5 \text{ V}$	t_{PHL}	-	2.6	-	μs	
Propagation L to H	$I_F = 10 \text{ mA}$, $V_{CC} = 5.0 \text{ V}$, $R_L = 1 \text{ k}\Omega$, $V_{TH} = 1.5 \text{ V}$	t_{PLH}	-	7.2	-	μs	

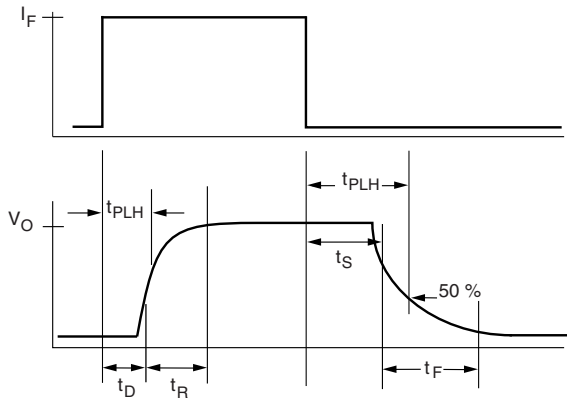
COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Common mode rejection, output high	$V_{CM} = 50 V_{P-P}$, $R_L = 1.0 \text{ k}\Omega$, $I_F = 0 \text{ mA}$	CM _H	-	5000	-	V/ μs	
Common mode rejection, output low	$V_{CM} = 50 V_{P-P}$, $R_L = 1.0 \text{ k}\Omega$, $I_F = 10 \text{ mA}$	CM _L	-	5000	-	V/ μs	

SAFETY AND INSULATION RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	$t = 1 \text{ min}$	V_{ISO}	4420	V_{RMS}
Isolation test voltage	$t = 1.0 \text{ s}$	V_{ISO}	5300	V_{RMS}
Maximum transient isolation voltage		V_{IOTM}	10 000	V_{peak}
Maximum repetitive peak isolation voltage		V_{IORM}	890	V_{peak}
Isolation resistance	$V_{IO} = 500 \text{ V}$, $T_{amb} = 25 \text{ }^\circ\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500 \text{ V}$, $T_{amb} = 100 \text{ }^\circ\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Output safety power		P_{SO}	400	mW
Input safety current		I_{SI}	275	mA
Safety temperature		T_s	175	$^\circ\text{C}$
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

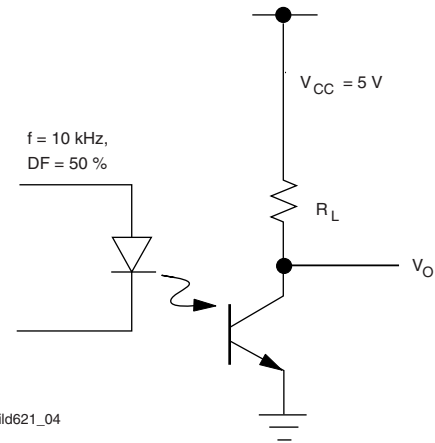
- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)



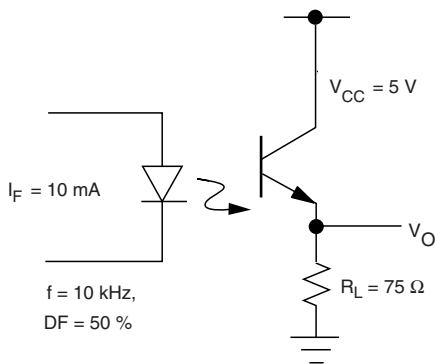
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Fig. 1 - Non-Saturated Switching Timing



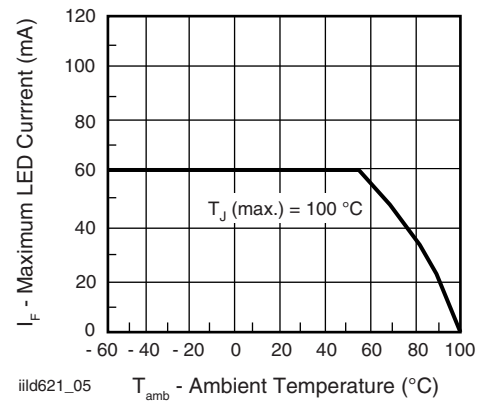
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Fig. 4 - Saturated Switching Timing



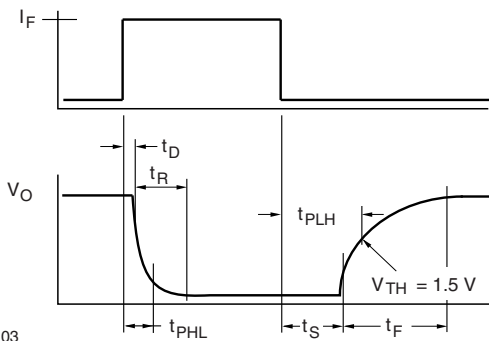
iiild621_02

Fig. 2 - Non-Saturated Switching Timing



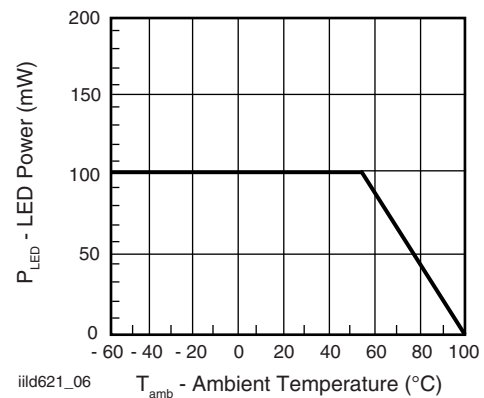
iiild621_05

Fig. 5 - Maximum LED Current vs. Ambient Temperature



iiild621_03

Fig. 3 - Saturated Switching Timing



iiild621_06

Fig. 6 - Maximum LED Power Dissipation

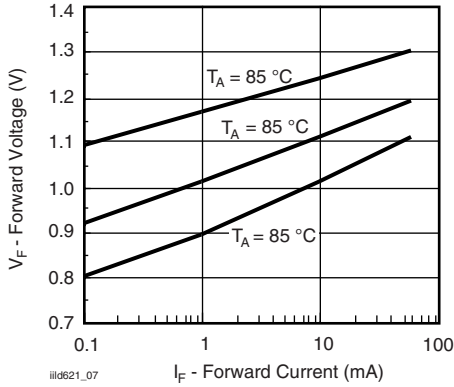


Fig. 7 - Forward Voltage vs. Forward Current

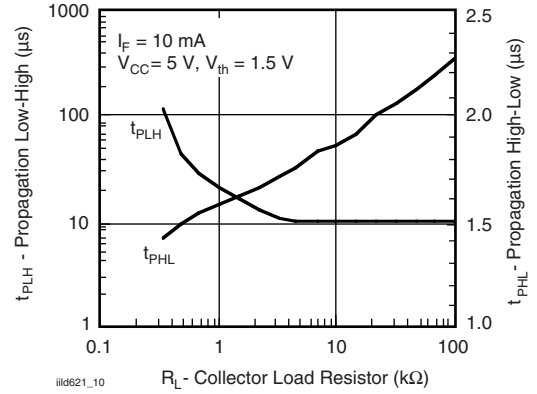


Fig. 10 - Propagation Delay vs. Collector Load Resistor

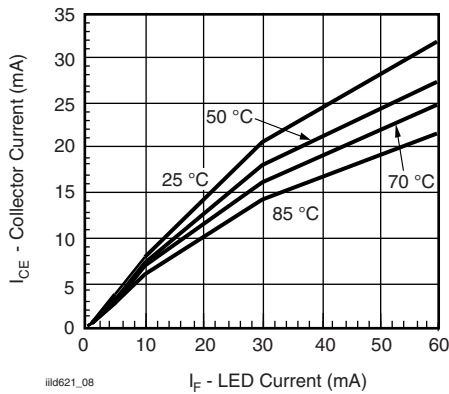


Fig. 8 - Collector Emitter Current vs. Temperature and LED Current

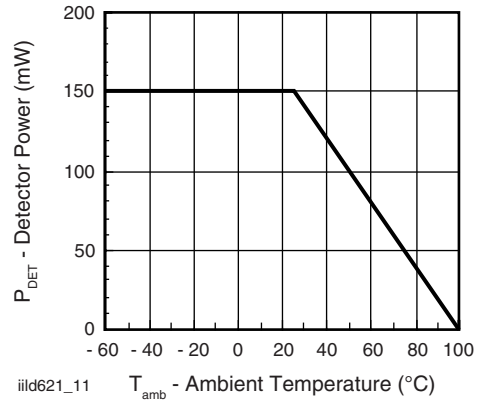


Fig. 11 - Maximum Detector Power Dissipation

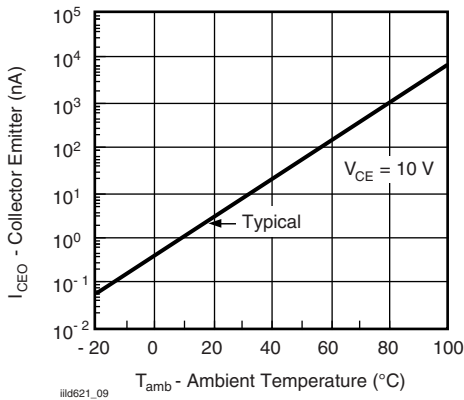


Fig. 9 - Collector Emitter Leakage vs. Temperature

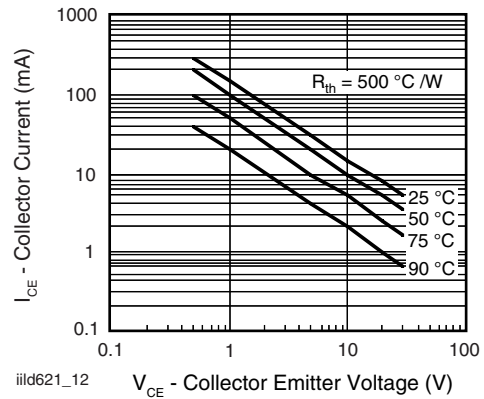


Fig. 12 - Maximum Collector Current vs. Collector Voltage

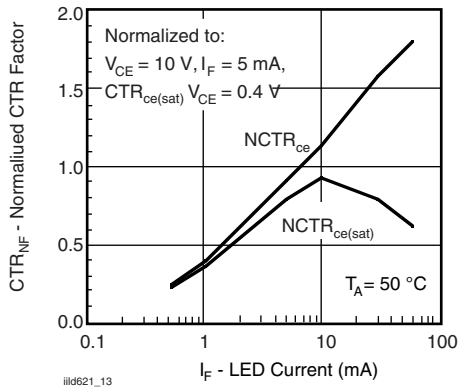


Fig. 13 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_F

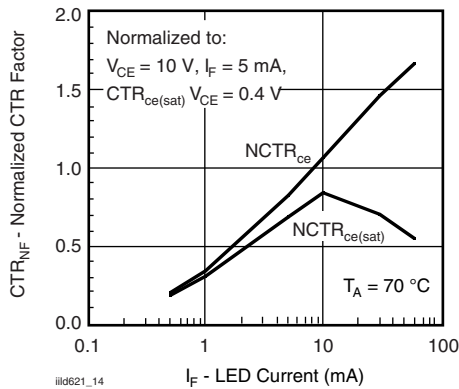


Fig. 14 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_F

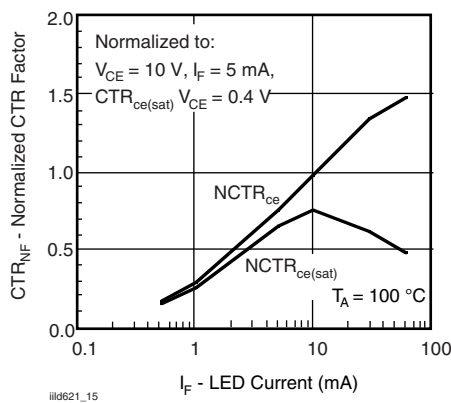
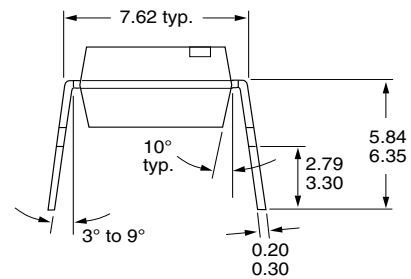
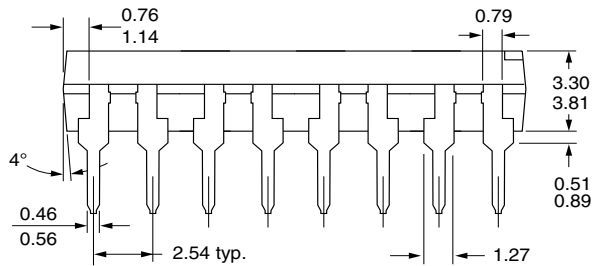
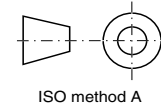
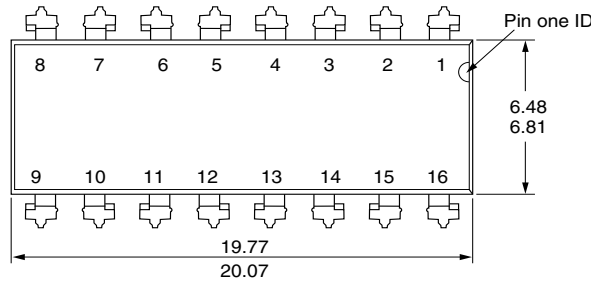
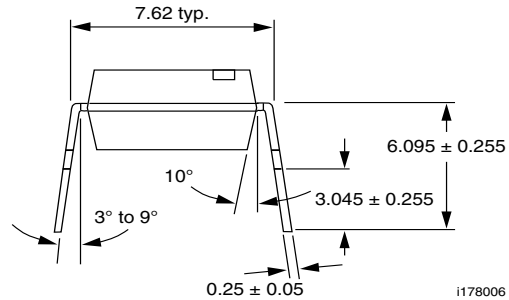
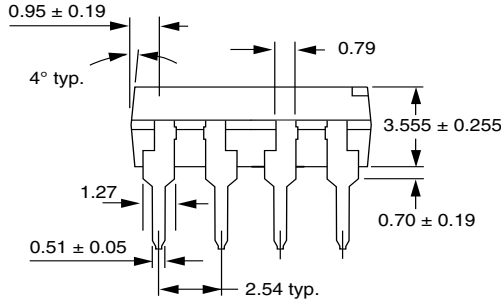
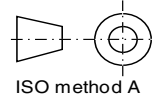
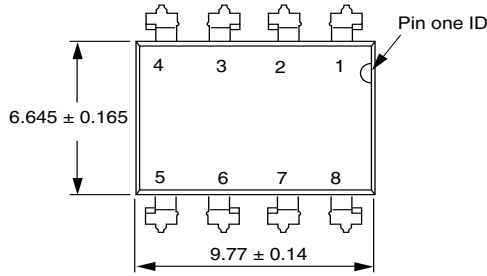


Fig. 15 - Normalization Factor for Non-Saturated and Saturated CTR vs. I_F

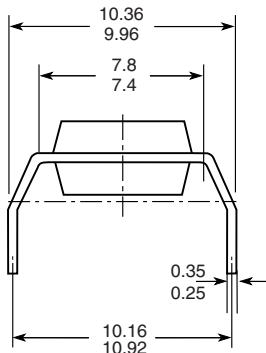


PACKAGE DIMENSIONS in millimeters

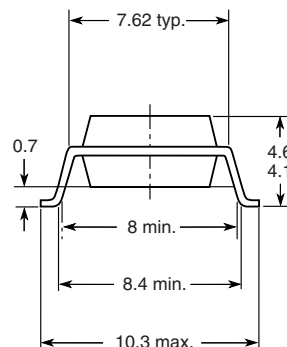


i178007

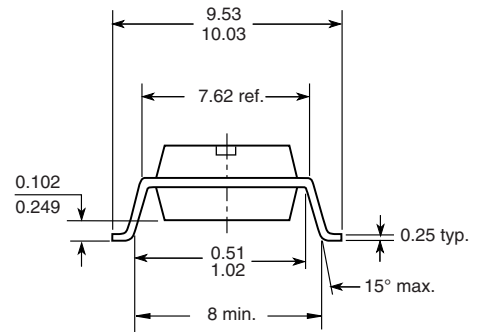
Option 6



Option 7



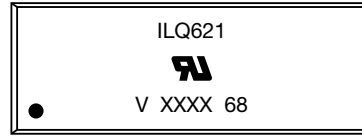
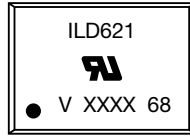
Option 9



18450



PACKAGE MARKING



Note

- XXXX = LMC (lot marking code)



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